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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/955,388	09/17/2001	Yoo-Sang Hwang	9898-189	9987	
7:	590 12/16/2002				
MARGER JOHNSON & McCOLLOM, P.C.			EXAMINER		
1030 S.W. Mor Portland, OR	· - • · · · · · · · · · · · · · · · · ·		MAI, ANH D		
	•		ART UNIT	PAPER NUMBER	
			2814		
			DATE MAILED: 12/16/2002		

Please find below and/or attached an Office communication concerning this application or proceeding.

••	Application No.	Applicant(s)	4 h			
	09/955,388	HWANG ET AL.				
Office Action Summary	Examiner	Art Unit				
	Anh D. Mai	2814				
- The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).						
1) Responsive to communication(s) filed on <u>02 C</u>	October 2002 .					
2a)⊠ This action is FINAL . 2b)□ Thi	s action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. Disposition of Claims						
4) Claim(s) 1-15 is/are pending in the application						
4a) Of the above claim(s) 1-4 is/are withdrawn t	from consideration.					
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>5-15</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
9) The specification is objected to by the Examiner						
10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action. 12) The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120	armior.					
13) Acknowledgment is made of a claim for foreign	priority under 35 LLC C & 410/o) (d) or (f)				
a) ☐ All b) ☐ Some * c) ☐ None of:	priority under 33 0.3.0. § 119(a)-(a) or (i).				
, , ,	s have been received					
_		on No				
<u> </u>	2. Certified copies of the priority documents have been received in Application No					
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.						
14) Acknowledgment is made of a claim for domestic	priority under 35 U.S.C. § 119(e	e) (to a provisional	application).			
a) The translation of the foreign language provisional application has been received. 15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachment(s)						
Notice of References Cited (PTO-892) Interview Summary (PTO-413) Paper No(s) Notice of Draftsperson's Patent Drawing Review (PTO-948) Notice of Informal Patent Application (PTO-152) Information Disclosure Statement(s) (PTO-1449) Paper No(s) Other:						
S. Patent and Trademark Office						

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DETAILED ACTION

Amendment

1. Amendment filed October 2, 2002 has been entered as Paper No. 5. Claim 5 have been amended. Claims 13-15 have been added. Claims 1-4 have been withdrawn. Claims 1-15 are pending.

Response to Amendment

2. The amendment filed October 2, 2002 is objected to under 35 U.S.C. 132 because it introduces new matter into the disclosure. 35 U.S.C. 132 states that no amendment shall introduce new matter into the disclosure of the invention. The added material which is not supported by the original disclosure is as follows: "wherein the first sub-plug fills a lower portion of the contact hole to a level substantially below a top surface of the insulating layer".

Applicant is required to cancel the new matter in the reply to this Office Action.

Claim Rejections - 35 USC § 112

The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

3. Claims 5-15 are rejected under 35 U.S.C. 112, first paragraph, as containing subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention.

There does not appear to be a written description of the claim limitation "wherein the first sub-plug fills a lower portion of the contact hole to a level substantially below a top surface of the insulating layer" in the application as filed.

Claim Rejections - 35 USC § 102

The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.

4. Claims 5-8, 10-12 and 14 are rejected under 35 U.S.C. 102(e) as being clearly anticipated by Lim et al. (U.S. Patent No. 6,380,084) (cited previously).

With respect to claim 5, as best understood by the examiner, Lim teaches a method for manufacturing a semiconductor device as claimed including:

forming an insulating layer (52) having a contact hole therethrough on a semiconductor substrate (40);

forming a diffusion barrier layer (56/60) on a surface of insulating layer (52) and on surfaces within the contact hole; and

forming a contact plug in the contact hole by forming a first sub-plug (64) that fills a lower portion of the contact hole and forming a second sub-plug (68) that fills an upper portion of the contact hole on the first sub-plug (64),

wherein the first sub-plug (64) fill the lower portion of the contact hole to a level substantially below a top surface of the insulating layer. (See Figs. 15-16).

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With respect to claim 6, the formation of the first sub-plug (64) of Linn comprises forming a first metal layer (64) on the insulating layer (52) having the contact hole (66) therethrough and etching back the first metal layer (64) to a predetermined depth (85) to expose a void in the first metal layer, if any.

With respect to claims 7 and 8, the formation of the second sub-plug (68) of Lin comprises forming a second metal layer (68) on the semiconductor substrate on which the first sub-plug (64) has been formed and polishing the second metal layer (68) so as to expose a top surface of the diffusion barrier layer (56/60) on the insulating layer (52).

With respect to claim 10, the second sub-plug of Linn is formed of a material as claimed.

With respect to claim 11, the second sub-plug (68) is formed to a thickness as claimed.

With respect to claim 12, the diffusion barrier layer (56/60) is formed of a material as claimed.

With respect to claim 14, since the first metal layer (64) may also be deposited by CVD, thus the metal layer (64) is capable of generating a void.

Claim Rejections - 35 USC § 103

The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.

Claims 9 and 13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Linn '084 as applied to claim 5 above, and further in view of Lee et al. (U.S. Patent No. 5,801,096).
With respect to claim 9, Lim formed the first sub-plug (64).

Thus, Lim is shown to teach all the features of the claim with the exception of using tungsten.

However, Lee teaches that using tungsten (10/16) to fill the contact plug (9) are well known in the art to form a conductive plug.

Therefore, it would have been obvious to one having ordinary skill in the art at the time of invention to form the first sub-plug (64) of Lim using tungsten as taught by Lee to provide electrical contact to the lower portion of the semiconductor substrate.

With respect to claim 13, the contact plug formed in the contact hole of Lim, in view of Lee, can be made to contact surface of the semiconductor substrate (1).

6. Claim 15 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lim '084 as applied to claim 8 above, and further in view of Grill et al. (U.S. Pub. No. 2002/0127844).

Lim teaches depositing a second metal layer (68) filling the upper portion of the contact plug.

Thus, Lim is shown to teach all the features of the claim with the exception of explicitly using atomic layer deposition.

However, Grill in a method for making a semiconductor device teaches: a conductive materials may be formed by various method well known to those skilled in the art including: CVD, plating and atomic layer deposition. (See [0042]).

Therefore, it would have been obvious to one having ordinary skill in the art at the time of invention to form the second metal layer (68) of Lim using atomic layer deposition as taught by Grill to avoid a defect such as a seam formation in the conductive layer.

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Response to Arguments

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7. Applicant's arguments with respect to claims 5-12 have been considered but are moot in

view of the new ground(s) of rejection.

Although the same references applied, the arguments are moot because new limitations

have been added to the claims.

Conclusion

8. Applicant's amendment necessitated the new ground(s) of rejection presented in this

Office action. Accordingly, THIS ACTION IS MADE FINAL. See MPEP § 706.07(a).

Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE

MONTHS from the mailing date of this action. In the event a first reply is filed within TWO

MONTHS of the mailing date of this final action and the advisory action is not mailed until after

the end of the THREE-MONTH shortened statutory period, then the shortened statutory period

will expire on the date the advisory action is mailed, and any extension fee pursuant to 37

CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event,

however, will the statutory period for reply expire later than SIX MONTHS from the date of this

final action.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Anh D. Mai whose telephone number is (703) 305-0575. The

examiner can normally be reached on 8:30AM-5:00PM.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (703) 308-4918. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

A.M December 9, 2002

SUPERVISORY DEMANDY EXAMINER